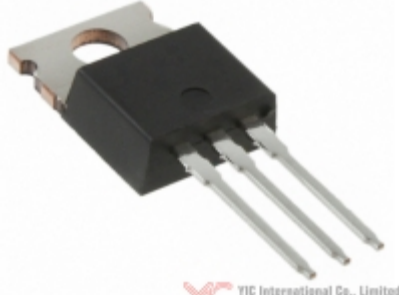


	<h2>IRFBE30PBF</h2>
	<p>Hersteller-Teilenummer: IRFBE30PBF</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 800V 4.1A TO-220AB</p> <p>Datenblätter: 1.IRFBE30PBF.pdf 2.IRFBE30PBF.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 4244 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	IRFBE30PBF
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 800V 4.1A TO-220AB
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	4244 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220AB
Verlustleistung (max)	125W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	800V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	4.1A (Tc)
Rds On (Max) @ Id, Vgs	3 Ohm @ 2.5A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	78nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1300pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±20V
Verpackung	Tube

IRFBE30PBF ist neu im Original, Suche IRFBE30PBF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IRFBE30PBF Vishay / Siliconix mit Garantie und Vertrauen.
Anfrage IRFBE30PBF: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>IRFBE30L Electro-Films (EFI) / Vishay MOSFET N-CH 800V 4.1A TO-262</p>	 <p>IRFBE30LPBF Electro-Films (EFI) / Vishay MOSFET N-CH 800V 4.1A TO-262</p>	 <p>IRFBE30SPBF Electro-Films (EFI) / Vishay MOSFET N-CH 800V 4.1A D2PAK</p>	 <p>IRFBE30SPBF Vishay / Siliconix MOSFET N-CH 800V 4.1A D2PAK</p>
 <p>IRFBE30PBF Electro-Films (EFI) / Vishay MOSFET N-CH 800V 4.1A TO-220AB</p>	 <p>IRFBE30S Electro-Films (EFI) / Vishay MOSFET N-CH 800V 4.1A D2PAK</p>	 <p>IRFBE30LPBF Vishay / Siliconix MOSFET N-CH 800V 4.1A TO-262</p>	 <p>IRFBE30L Vishay / Siliconix MOSFET N-CH 800V 4.1A TO-262</p>

heiße Teile

Mehr

IRFBC40ASTRRPBF	IRFBC40F	IRFBC40LC	IRFBC40LC	IRFBC40LCPBF
IRFBC40LCPBF	IRFBC40LPBF	IRFBC40LPBF	IRFBC40S	IRFBC40S
IRFBC40SPBF	IRFBC40SPBF	IRFBC40STRL	IRFBC40STRL	IRFBC40STRLPBF
IRFBC40STRLPBF	IRFBC40STRR	IRFBC40STRR	IRFBC41LC	IRFBE20PBF
IRFBE20PBF	IRFBE20SPBF	IRFBE30L	IRFBE30L	IRFBE30LPBF-M
IRFBE30PBF	IRFBE30SPBF	IRFBE30SPBF	IRFBE30STRLPBF	IRFBE30STRLPBF
IRFBF20LPBF	IRFBF20LPBF	IRFBF20STRL	IRFBF20STRL	IRFBF20STRLPBF
IRFBF20STRLPBF	IRFBG20PBF	IRFBG20PBF	IRFBG30PBF	IRFBG30PBF
IRFBL10N60A	IRFC480LCD	IRFD010PBF	IRFD010PBF	IRFD020PBF
IRFD020PBF	IRFD110PBF	IRFD110PBF	IRFD120PBF	IRFD120PBF

Contact us: Info@Y-IC.com

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